

DL-3147-161(-261)

Index Guided AlGaInP Laser Diode

Overview

DL-3147-161(-261) is index guided 650 nm (Typ.) AlGaInP laser diode with low threshold current and high operating temperature. The low threshold current and high operating temperature are achieved by a strained multiple quantum well active layer. DL-3147-161(-261) is suitable for applications such as optical disc systems (DVD-ROM) and other optical information systems.

Features

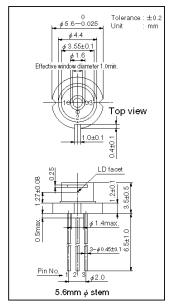
· Short wavelength : 650 nm (Typ.) · Low threshold current : Ith = 45 mA (Typ.) · High operating temperature : 70 ℃ at 5 mW

· TE mode

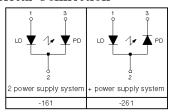
Absolute Maximum Ratings at Tc=25℃

Parameter		Symbol	Ratings	Unit	
Light Output		Po	7	mW	
Reverse Voltage	Laser PIN	VR	30	V	
Operating Temperature		Topr	-10 to +70	$^{\circ}\mathbb{C}$	
Storage Temperature		Tstg	-40 to +85	$^{\circ}$	

Package Dimensions



Electrical Connection

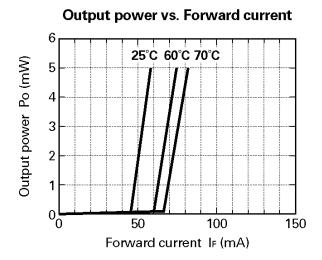


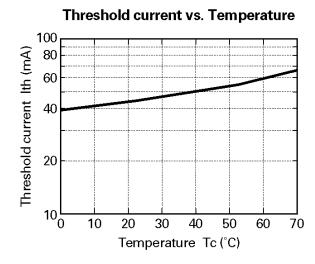
Electrical and Optical Characteristics at Tc=25°C

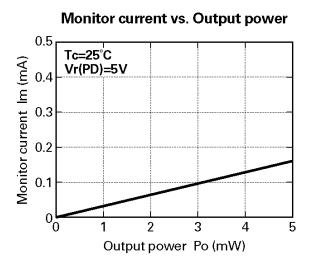
Para	meter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshol	d Current	Ith	CW	_	45	65	mA
Operating	g Current	Iop	Po=5mW	_	60	80	mA
Operatin	g Voltage	Vop	Po=5mW	_	2.2	2.5	V
Lasing W	avelength	λp	Po=5mW	_	650	660	nm
Beam 💥)	Perpendicular	$\theta \perp$	Po=5mW	25	30	40	deg.
Divergence	Parallel	θ //	Po=5mW	6	7.5	10	deg.
Off Axis	Perpendicular	$\Delta \theta \perp$	_	-	-	±3	deg.
Angle	Parallel	$\Delta heta$ //	-	-	-	±2	deg.
Differential	Efficiency	dPo/dIop	_	0.15	0.35	_	mW/mA
Monitoring C	utput Current	Im	Po=5mW	0.05	0.15	0.5	mA
Astign	natism	As	Po=5mW	1	8	_	μm

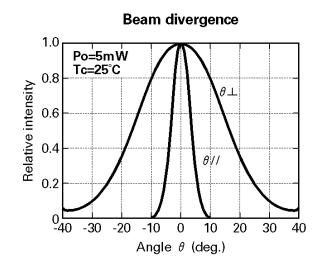
^{※)} Full angle at half maximum note: The above product specifications are subject to change without notice.

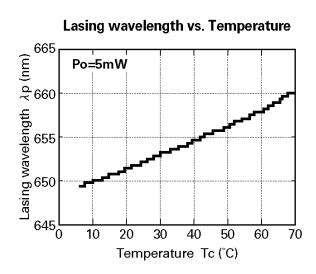
Characteristics

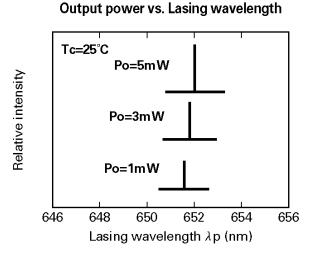














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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

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